## PNP Silicon AF Transistors

- For general AF applications
- High current gain
- Low collector-emitter saturation voltage
- Complementary types: BCW66... (NPN)
- Pb-free (RoHS compliant) package

- Qualified according AEC Q101


| Type | Marking | Pin Configuration |  |  | Package |
| :--- | :--- | :--- | :--- | :--- | :--- |
| BCW67A | DAs | $1=\mathrm{B}$ | $2=\mathrm{E}$ | $3=\mathrm{C}$ | SOT23 |
| BCW67B | DBs | $1=\mathrm{B}$ | $2=\mathrm{E}$ | $3=\mathrm{C}$ | SOT23 |
| BCW67C | DCs | $1=\mathrm{B}$ | $2=\mathrm{E}$ | $3=\mathrm{C}$ | SOT23 |
| BCW68F | DFs | $1=\mathrm{B}$ | $2=\mathrm{E}$ | $3=\mathrm{C}$ | SOT23 |
| BCW68G | DGs | $1=\mathrm{B}$ | $2=\mathrm{E}$ | $3=\mathrm{C}$ | SOT23 |
| BCW68H | DHs | $1=\mathrm{B}$ | $2=\mathrm{E}$ | $3=\mathrm{C}$ | SOT23 |

## Maximum Ratings

| Parameter | Symbol | Value | Unit |
| :--- | :--- | :---: | :--- |
| Collector-emitter voltage | $V_{\mathrm{CEO}}$ |  | V |
| BCW67 |  | 32 |  |
| BCW68 |  | 45 |  |
| Collector-base voltage | $V_{\mathrm{CBO}}$ |  |  |
| BCW67 |  |  |  |
| BCW68 |  | 60 |  |
| Emitter-base voltage | $V_{\mathrm{EBO}}$ | 5 |  |
| Collector current | $I_{\mathrm{C}}$ | 800 | mA |
| Peak collector current, $t_{\mathrm{p}} \leq 10 \mathrm{~ms}$ | $I_{\mathrm{CM}}$ | 1 | A |
| Base current | $I_{\mathrm{B}}$ | 100 | mA |
| Peak base current | $I_{\mathrm{BM}}$ | 200 |  |
| Total power dissipation, $T_{\mathrm{S}} \leq 79^{\circ} \mathrm{C}$ | $P_{\text {tot }}$ | 330 | mW |
| Junction temperature | $T_{\mathrm{j}}$ | 150 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature | $T_{\text {stg }}$ | $-65 \ldots 150$ |  |

Thermal Resistance

| Parameter | Symbol | Value | Unit |
| :--- | :--- | :--- | :--- |
| Junction - soldering point ${ }^{1}$ ) | $R_{\text {thJS }}$ | $\leq 215$ | K/W |

${ }^{1}$ For calculation of $R_{\text {thJA }}$ please refer to Application Note AN077 (Thermal Resistance Calculation)

Electrical Characteristics at $T_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise specified

| Parameter | Symbol | Values |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | min. | typ. | max. |  |
| DC Characteristics |  |  |  |  |  |
| Collector-emitter breakdown voltage $\begin{aligned} & I_{\mathrm{C}}=10 \mathrm{~mA}, I_{\mathrm{B}}=0, \mathrm{BCW} 67 \\ & I_{\mathrm{C}}=10 \mathrm{~mA}, I_{\mathrm{B}}=0, \mathrm{BCW} 68 \end{aligned}$ | $V_{(\mathrm{BR}) \mathrm{CEO}}$ | $\begin{aligned} & 32 \\ & 45 \end{aligned}$ |  |  | V |
| Collector-base breakdown voltage $\begin{aligned} & I_{C}=10 \mu \mathrm{~A}, I_{\mathrm{E}}=0, \mathrm{BCW} 67 \\ & I_{\mathrm{C}}=10 \mu \mathrm{~A}, I_{\mathrm{E}}=0, \mathrm{BCW} 68 \end{aligned}$ | $V_{(\mathrm{BR}) \mathrm{CBO}}$ | $\begin{aligned} & 45 \\ & 60 \end{aligned}$ |  |  |  |
| Emitter-base breakdown voltage $I_{E}=10 \mu \mathrm{~A}, I_{C}=0$ | $V_{(\mathrm{BR}) \mathrm{EBO}}$ | 5 | - | - |  |
| Collector-base cutoff current $\begin{aligned} & V_{\mathrm{CB}}=32 \mathrm{~V}, I_{\mathrm{E}}=0 \\ & V_{\mathrm{CB}}=45 \mathrm{~V}, I_{\mathrm{E}}=0 \\ & V_{\mathrm{CB}}=32 \mathrm{~V}, I_{\mathrm{E}}=0, T_{\mathrm{A}}=150^{\circ} \mathrm{C} ; \mathrm{BCW} 67 \\ & V_{\mathrm{CB}}=45 \mathrm{~V}, I_{\mathrm{E}}=0, T_{\mathrm{A}}=150^{\circ} \mathrm{C} ; \mathrm{BCW} 68 \end{aligned}$ | $I_{\text {CBO }}$ |  |  | $\begin{gathered} 0.02 \\ 0.02 \\ 20 \\ 20 \end{gathered}$ | $\mu \mathrm{A}$ |
| Emitter-base cutoff current $V_{\mathrm{EB}}=4 \mathrm{~V}, I_{\mathrm{C}}=0$ | IEbo | - | - | 20 | nA |
| DC current gain ${ }^{1)}$ | $h_{\text {FE }}$ | 35 50 80 75 120 180 100 160 250 35 60 100 |  |  | - |

## DC Electrical Characteristics

| Parameter | Symbol | Values |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | min. | typ. | max. |  |
| Characteristics |  |  |  |  |  |
| Collector-emitter saturation voltage ${ }^{1)}$ $\begin{aligned} & I_{\mathrm{C}}=100 \mathrm{~mA}, I_{\mathrm{B}}=10 \mathrm{~mA} \\ & I_{\mathrm{C}}=500 \mathrm{~mA}, I_{\mathrm{B}}=50 \mathrm{~mA} \end{aligned}$ | $V_{\text {CEsat }}$ | - | - | $\begin{aligned} & 0.3 \\ & 0.7 \end{aligned}$ | V |
| Base emitter saturation voltage ${ }^{1)}$ $\begin{aligned} & I_{\mathrm{C}}=100 \mathrm{~mA}, I_{\mathrm{B}}=10 \mathrm{~mA} \\ & I_{\mathrm{C}}=500 \mathrm{~mA}, I_{\mathrm{B}}=50 \mathrm{~mA} \end{aligned}$ | $V_{\text {BEsat }}$ | - | - | $\begin{gathered} 1.25 \\ 2 \end{gathered}$ |  |

## AC Characteristics

| Transition frequency <br> $I_{\mathrm{C}}=50 \mathrm{~mA}, V_{\mathrm{CE}}=5 \mathrm{~V}, f=20 \mathrm{MHz}$ | $f_{\mathrm{T}}$ | - | 200 | - | MHz |
| :--- | :--- | :---: | :---: | :---: | :---: |
| Collector-base capacitance <br> $V_{\mathrm{CB}}=10 \mathrm{~V}, f=1 \mathrm{MHz}$ | $\mathrm{C}_{\mathrm{cb}}$ | - | 6 | - | pF |
| Emitter-base capacitance <br> $V_{\mathrm{EB}}=0.5 \mathrm{~V}, f=1 \mathrm{MHz}$ | $\mathrm{C}_{\mathrm{eb}}$ | - | 60 | - |  |

[^0]DC current gain $h_{\text {FE }}=f\left(I_{\mathrm{C}}\right)$
$V_{C E}=1 \mathrm{~V}$


Base-emitter saturation voltage
$I_{\mathrm{C}}=f\left(V_{\mathrm{BEsat}}\right), h_{\mathrm{FE}}=10$


## Collector-emitter saturation voltage

$I_{\mathrm{C}}=f\left(V_{\text {CEsat }}\right), h_{\text {FE }}=10$


Collector cutoff current $I_{\mathrm{CBO}}=f\left(T_{\mathrm{A}}\right)$
$V_{\mathrm{CBO}}=25 \mathrm{~V}$


Transition frequency $f_{\mathrm{T}}=f\left(I_{\mathrm{C}}\right)$
$V_{C E}=5 \mathrm{~V}$


Total power dissipation $P_{\text {tot }}=f\left(T_{\mathrm{S}}\right)$


Collector-base capacitance $C_{\mathrm{cb}}=f\left(V_{\mathrm{CB}}\right)$
Emitter-base capacitance $C_{\mathrm{eb}}=f\left(V_{\mathrm{EB}}\right)$


## Permissible Pulse Load

$$
P_{\text {totmax }} / P_{\text {totDC }}=f\left(t_{\mathrm{p}}\right)
$$



Package Outline


1) Lead width can be 0.6 max. in dambar area

Foot Print


Marking Layout (Example)


Standard Packing
Reel $\varnothing 180 \mathrm{~mm}=3.000$ Pieces/Reel
Reel $\varnothing 330 \mathrm{~mm}=10.000$ Pieces/Reel


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[^0]:    ${ }^{1}$ Pulse test: $\mathrm{t}<300 \mu \mathrm{~s} ; \mathrm{D}<2 \%$

